



50V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

50 V

Current

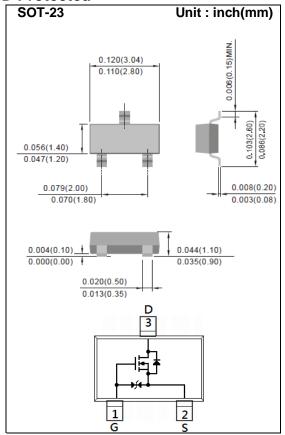
500mA

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@500mA<1.45\Omega$
- R_{DS(ON)}, V_{GS}@4.5V, I_D@200mA<1.95Ω
- R_{DS(ON)}, V_{GS}@2.5V, I_D@100mA<4.0Ω
- $R_{DS(ON)}$, $V_{GS}@1.8V$, $I_{D}@10mA<6.0\Omega$
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc
- ESD Protected 2KV HBM
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	50	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current		I _D	500	mA	
Pulsed Drain Current		I _{DM}	1200		
Power Dissipation	T _A =25°C	P_{D}	500	mW	
	Derate above 25°C		4	mW/°C	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	250	°C/W	

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Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I_D =250uA	50	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.5	0.86	1.0	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =500mA	-	1.2	1.45	Ω
		V _{GS} =4.5V,I _D =200mA	-	1.3	1.95	
		V _{GS} =2.5V,I _D =100mA	-	1.7	4.0	
		V _{GS} =1.8V,I _D =10mA	-	4.0	6.0	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =50V,V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 10	
Dynamic (Note 5)						
Total Gate Charge	Q_g	V _{DS} =25V, I _D =500mA, V _{GS} =4.5V	-	0.95	-	nC
Gate-Source Charge	Q_gs		-	0.34	-	
Gate-Drain Charge	Q_{gd}		-	0.32	-	
Input Capacitance	Ciss), OE),), O),	-	36	-	pF
Output Capacitance	Coss	V _{DS} =25V, V _{GS} =0V,	-	11	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	6.6	-	
Turn-On Delay Time	td _(on)	\/ O5\/ 500 ·· A	-	2.3	-	ns
Turn-On Rise Time	tr	$\begin{array}{c} V_{DD}{=}25V,\ I_{D}{=}500mA,\\ V_{GS}{=}10V,\\ R_{G}{=}6\Omega \end{array}$	-	20	-	
Turn-Off Delay Time	td _(off)		-	7	-	
Turn-Off Fall Time	tf		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	500	mA
Diode Forward Voltage	V_{SD}	I _S =500mA, V _{GS} =0V	-	0.9	1.5	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

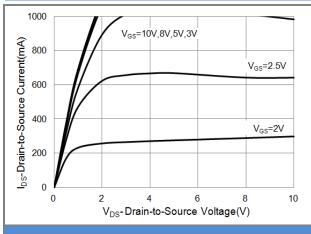


Fig.1 On-Region Characteristics

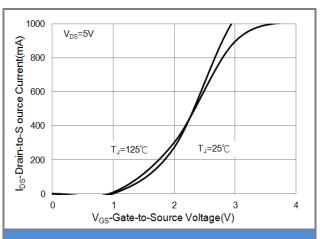


Fig.2 Transfer Characteristics

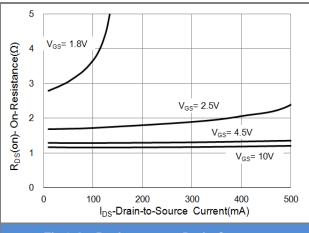


Fig.3 On-Resistance vs. Drain Current

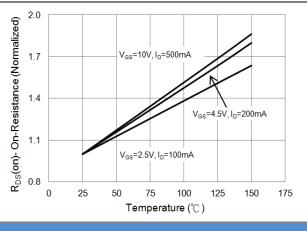
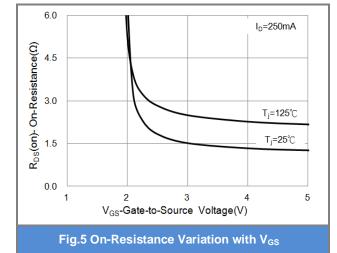
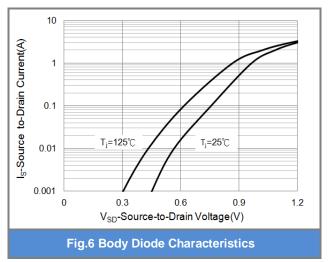


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

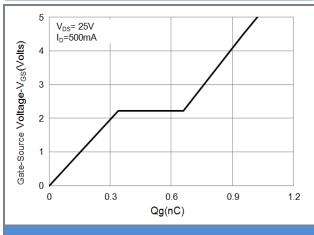
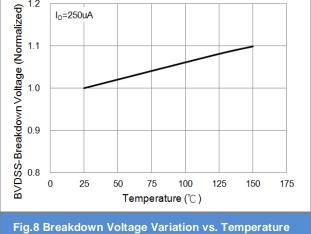


Fig.7 Gate-Charge Characteristics



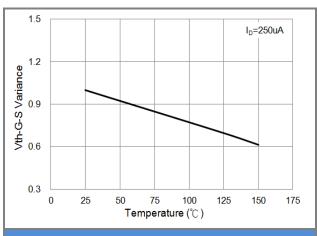


Fig.9 Threshold Voltage Variation with Temperature

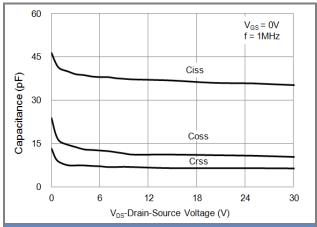


Fig.10 Capacitance vs. Drain-Source Voltage

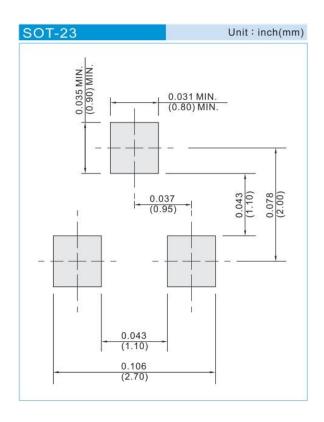




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3438-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A38	Halogen free

Mounting Pad Layout







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